

1.6 Ω On Resistance, ± 5 V, +12 V, and +3 V Quad SPST Switches

DESCRIPTION

The DG9424E, DG9425E, DG9426E are monolithic quad single-pole-single-throw analog switches. The G9424E and DG9425E differ only in that they respond to opposite logic levels. The DG9426E has two normally open and two normally closed switches. It can be given various configurations, including four SPST, two SPDT, and one DPDT.

Using BiCMOS wafer fabrication technology allows the DG9424E, DG9425E, and DG9426E to operate on single and dual supplies. Single supply voltage ranges from 3 V to 16 V while dual supply operation is recommended with ± 3 V to ± 8 V. Each switch conducts equally well in both direction when on, and blocks input voltages up to the supply levels when off.

The low and flat on resistance over the full input signal voltage rang bring excellent linearity, reduce insertion loss and signal distortion, make them ideal for data acquisition and programmable gain control applications. These switch characters also make them ideal fit for audio signal switch and reed relay replacement.

The DG9424E, DG9425E, DG9426E feature low power dissipation, fast switching speed, and low voltage logic control threshold. Proprietary design enables the low charge injection that minimize the switching transient.

Operation temperature is specified from -40 $^{\circ}\text{C}$ to $+85$ $^{\circ}\text{C}$. The DG9424E, DG9425E, DG9426E are available in 16 lead TSSOP packages.

FEATURES

- 3 V to 16 V single supply or ± 3 V thru ± 8 V dual supply operation
- 1.6 Ω typical on resistance
- 3 V logic compatible for control
- Bi-directional rail to rail signal switching
- Fast switching speed
- < 0.2 nA switch on leakage
- Break-before-make switching - DG9426

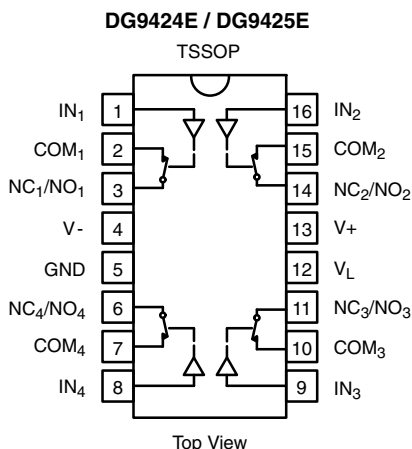
BENEFITS

- Wide operation voltage range
- Low signal errors and distortion
- Fast switching time
- Simple interfacing

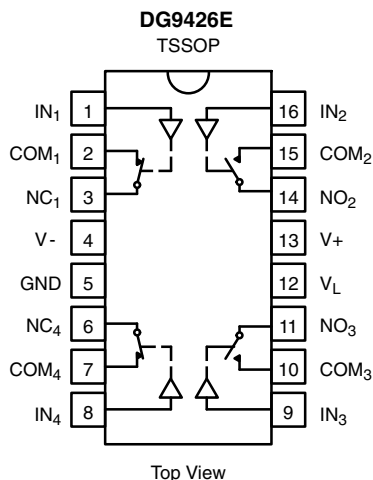
APPLICATIONS

- Automatic test equipment
- Data acquisition systems
- Meters and instruments
- Medical and healthcare systems
- Communication systems
- Audio and video signal routing
- Relay replacement
- Battery powered systems
- Computer peripherals
- Audio and video signal routing

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



TRUTH TABLE		
LOGIC	DG9424E	DG9425E
0	OFF	ON
1	ON	OFF

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION

TRUTH TABLE

LOGIC	SW ₁ , SW ₄	SW ₂ , SW ₃
0	ON	OFF
1	OFF	ON

ORDERING INFORMATION

TEMP. RANGE	PACKAGE	PART NUMBER	PART MARKING	STD PACK QUANTITY
-40 °C to +85 °C	16-Pin TSSOP	DG9424EDQ-T1-GE3	9424E	Tape and Reel 3000 Units
		DG9425EDQ-T1-GE3	9425E	Tape and Reel 3000 Units
		DG9426EDQ-T1-GE3	9426E	Tape and Reel 3000 Units

ABSOLUTE MAXIMUM RATINGS

PARAMETER	LIMIT	UNIT
V ₊ to V ₋	-0.3 to +18	V
GND to V ₋	18	
V _L	(GND - 0.3) to (V ₊) + 0.3	
IN, COM, NC, NO ^a	(V ₋) - 0.3 to (V ₊) + 0.3	
Continuous Current (NO, NC, COM Pins)	100	mA
Peak Current, S or D (Pulsed 1 ms, 10 % Duty Cycle)	200	
Storage Temperature	-65 to +150	°C
Power Dissipation (Package) ^b	16-Pin TSSOP ^c	450
Thermal Resistance ^b		178
ESD Human Body Model (HBM); per ANSI / ESDA / JEDEC® JS-001	>1500	V
Latch Up Current, per JESD78D	400	mA

Notes

- Signals on NC, NO, COM or IN exceeding V₊ or V₋ will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
- All leads welded or soldered to PC board.
- Derate 7 mW/°C above 25 °C.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



SPECIFICATIONS ^a Single Supply 12 V								
PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED V ₊ = 12 V, V ₋ = 0 V V _L = 5 V, V _{IN} = 2.4 V, 0.8 V ^f	TEMP. ^b	LIMITS -40 °C to +85 °C			UNIT	
				MIN. ^d	TYP. ^c	MAX. ^d		
Analog Switch								
Analog Signal Range ^e	V _{ANALOG}		Full	0	-	12	V	
On-Resistance	R _{ON}	V ₊ = 10.8 V, V ₋ = 0 V I _{NO} , I _{NC} = 50 mA, V _{COM} = 2/9 V	Room	-	1.6	3	Ω	
			Full	-	-	4		
Digital Control								
Input Current	I _{INL} or I _{INH}		Full	-1	0.01	1	μA	
Dynamic Characteristics								
Turn-On Time ^e	t _{ON}	R _L = 300 Ω, C _L = 35 pF V _{NO} , V _{NC} = 5 V, see fig. 2	Room	-	36	51	ns	
			Full	-	-	65		
Turn-Off Time ^e	t _{OFF}		Room	-	20	35		
			Full	-	-	44		
Break-Before-Make Time Delay ^e	t _D	DG9426E only, V _{NO} , V _{NC} = 5 V R _L = 300 Ω, C _L = 35 pF	Room	2	-	-		
Charge Injection ^e	Q _{INJ}	V _g = 0 V, R _g = 0 Ω, C _L = 1 nF	Room	-	38	-	pC	
Off-Isolation ^e	OIRR	R _L = 50 Ω, C _L = 5 pF f = 1 MHz	Room	-	-56	-	dB	
Channel-to-Channel Crosstalk ^e	X _{TALK}		Room	-	-77	-		
NO, NC Off Capacitance ^e	C _{NO(off)}	f = 1 MHz	Room	-	49	-	pF	
	C _{NC(off)}							
COM Off Capacitance ^e	C _{COM(off)}		Room	-	37	-		
Channel On Capacitance ^e	C _{COM(on)}		Room	-	89	-		
Power Supplies								
Positive Supply Current	I ₊	V _{IN} = 0 or V _L	Room	-	0.02	1	μA	
			Full	-	-	5		
Negative Supply Current	I ₋		Room	-1	-0.002	-		
			Full	-5	-	-		
Logic Supply Current	I _L		Room	-	0.002	1		
			Full	-	-	5		
Ground Current	I _{GND}		Room	-1	-0.002	-		
			Full	-5	-	-		



SPECIFICATIONS ^a Dual Supply ± 5 V							
PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED V+ = 5 V, V- = 5 V V _L = 5 V, V _{IN} = 2.4 V, 0.8 V ^f	TEMP. ^b	LIMITS -40 °C to +85 °C			UNIT
				MIN. ^d	TYP. ^c	MAX. ^d	
Analog Switch							
Analog Signal Range ^e	V _{ANALOG}		Full	-5		5	V
On-Resistance	R _{ON}	V+ = 4.5 V, V- = -4.5 V I _{NO} , I _{NC} = 50 mA	Room	-	1.9	3.3	Ω
			Full	-	-	4.3	
Switch Off Leakage Current	I _{NO(off)}	V+ = 5.5 V, V- = -5.5 V V _{COM} = ± 4.5 V, V _{NO} , V _{NC} = ± 4.5 V	Room	-1	-	1	nA
	I _{NC(off)}		Full	-10	-	10	
	I _{COM(off)}		Room	-1	-	1	
			Full	-10	-	10	
Channel On Leakage Current	I _{COM(on)}	V+ = 5.5 V, V- = -5.5 V, V _{NO} , V _{NC} = V _{COM} = ± 4.5 V	Room	-1	-	1	
			Full	-10	-	10	
Digital Control							
Input Current ^a	I _{INL} or I _{INH}		Full	-1	0.05	1	μA
Dynamic Characteristics							
Turn-On Time ^e	t _{ON}	R _L = 300 Ω, C _L = 35 pF V _{NO} , V _{NC} = ± 3.5 V, see fig. 2	Room	-	48	67	ns
			Full	-	-	81	
Turn-Off Time ^e	t _{OFF}		Room	-	34	57	
			Full	-	-	67	
Break-Before-Make Time Delay ^e	t _D	DG9426E only, V _{NO} , V _{NC} = 3.5 V R _L = 300 Ω, C _L = 35 pF	Room	2	-	-	
Charge Injection ^e	Q _{INJ}	V _g = 0 V, R _g = 0 Ω, C _L = 1 nF	Room	-	112	-	pC
Off Isolation ^e	OIRR	R _L = 50 Ω, C _L = 5 pF, f = 1 MHz	Room	-	-56	-	dB
Channel-to-Channel Crosstalk ^e	X _{TALK}		Room	-	-82	-	
Source Off Capacitance ^e	C _{NO(off)} C _{NC(off)}	f = 1 MHz	Room	-	38	-	pF
Drain Off Capacitance ^e	C _{COM(off)}		Room	-	38	-	
Channel On Capacitance ^e	C _{COM(on)}		Room	-	89	-	
Power Supplies							
Positive Supply Current ^e	I+	V _{IN} = 0 or V _L	Room	-	0.03	1	μA
			Full	-	-	5	
Negative Supply Current ^e	I-		Room	-1	-0.002	-	
			Full	-5	-	-	
Logic Supply Current ^e	I _L		Room	-	0.002	1	
			Full	-	-	5	
Ground Current ^e	I _{GND}		Room	-1	-0.002	-	
			Full	-5	-	-	



SPECIFICATIONS ^a Single Supply 5 V							
PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED V ₊ = 5 V, V ₋ = 0 V V _L = 5 V, V _{IN} = 2.4 V, 0.8 V ^f	TEMP. ^b	LIMITS -40 °C to +85 °C			UNIT
				MIN. ^d	TYP. ^c	MAX. ^d	
Analog Switch							
Analog Signal Range ^e	V _{ANALOG}		Full	-	-	5	V
On-Resistance ^e	R _{ON}	V ₊ = 4.5 V, I _{NO} , I _{NC} = 50 mA	Room	-	3.1	4.8	Ω
			Full	-	-	5.8	
Dynamic Characteristics							
Turn-On Time ^e	t _{ON}	R _L = 300 Ω, C _L = 35 pF V _{NO} , V _{NC} = 3.5 V, see fig. 2	Room	-	62	78	ns
			Hot	-	-	106	
Turn-Off Time ^e	t _{OFF}		Room	-	29	44	
			Hot	-	-	56	
Break-Before-Make Time Delay ^e	t _D	DG9426E only, V _{NO} , V _{NC} = 3.5 V R _L = 300 Ω, C _L = 35 pF	Room	5	-	-	
Charge Injection ^e	Q _{INJ}	V _g = 0 V, R _g = 0 Ω, C _L = 1 nF	Room	-	10	-	pC
Power Supplies							
Positive Supply Current ^e	I ₊	V _{IN} = 0 or V _L	Room	-	0.02	1	μA
			Hot	-	-	5	
Negative Supply Current ^e	I ₋		Room	-1	-0.002	-	
			Hot	-5	-	-	
Logic Supply Current ^e	I _L		Room	-	0.002	1	
			Hot	-	-	5	
Ground Current ^e	I _{GND}		Room	-1	-0.002	-	
			Hot	-5	-	-	



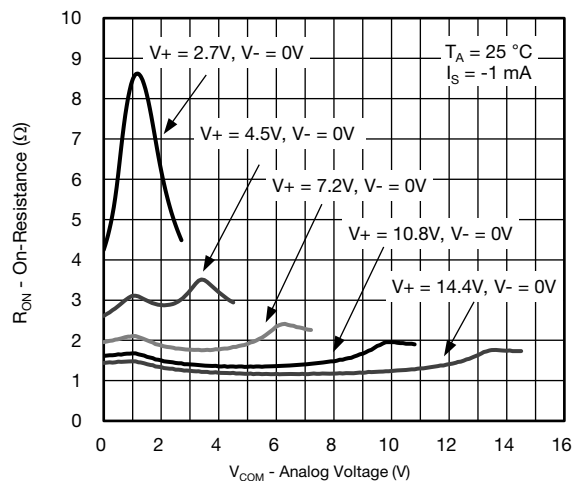
SPECIFICATIONS ^a Single Supply 3 V							
PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED V ₊ = 3 V, V ₋ = 0 V V _L = 3 V, V _{IN} = 2.4 V, 0.4 V ^f	TEMP. ^b	LIMITS -40 °C to +85 °C			UNIT
				MIN. ^d	TYP. ^c	MAX. ^d	
Analog Switch							
Analog Signal Range ^e	V _{ANALOG}		Full	0	-	3	V
On-Resistance	R _{ON}	V ₊ = 2.7 V, V ₋ = 0 V I _{NO} , I _{NC} = 5 mA, V _{COM} = 0.5, 2.2 V	Room	-	6	-	Ω
			Full	-	-	-	
Switch Off Leakage Current ^a	I _{NO(off)}	V ₊ = 3.3 V, V ₋ = 0 V V _{COM} = 0.3, 3 V, V _{NO} , V _{NC} = 3, 0.3 V	Room	-1	-	1	nA
	I _{NC(off)}		Full	-10	-	10	
	I _{COM(off)}		Room	-1	-	1	
			Full	-10	-	10	
Channel On Leakage Current ^a	I _{COM(on)}	V ₊ = 3.3 V, V ₋ = 0 V, V _{NO} , V _{NC} = V _{COM} = 0.3, 3 V	Room	-1	-	1	nA
			Full	-10	-	10	
Digital Control ^e							
Input Current	I _{INL} or I _{INH}		Full	-1	0.005	1	μA
Dynamic Characteristics							
Turn-On Time	t _{ON}	R _L = 300 Ω, C _L = 35 pF V _{NO} , V _{NC} = 1.5 V, see fig. 2	Room	-	140	-	ns
			Full	-	-	193	
Turn-Off Time	t _{OFF}		Room	-	65	-	
			Full	-	-	89	
Break-Before-Make Time Delay	t _D	DG9426E only, V _{NO} , V _{NC} = 1.5 V R _L = 300 Ω, C _L = 35 pF	Room	5			
Charge Injection ^e	Q _{INJ}	V _g = 0 V, R _g = 0 Ω, C _L = 1 nF	Room	-	15	-	pC
Off Isolation ^e	OIRR	R _L = 50 Ω, C _L = 5 pF f = 1 MHz	Room	-	-56	-	dB
Channel-to-Channel Crosstalk ^e	X _{TALK}		Room	-	-80	-	
Source Off Capacitance ^e	C _{NO(off)}	f = 1 MHz	Room	-	53	-	pF
	C _{NC(off)}						
Drain Off Capacitance ^e	C _{COM(off)}		Room	-	42	-	
Channel On Capacitance ^e	C _{COM(on)}		Room	-	92	-	

Notes

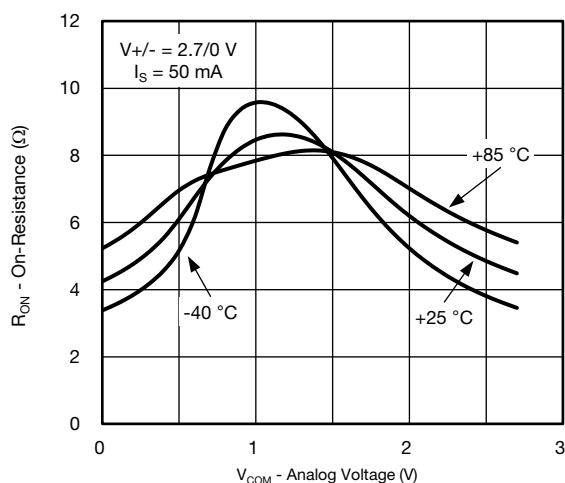
- a. Leakage parameters are guaranteed by worst case test conditions and not subject to production test.
- b. Room = 25 °C, Full = As determined by the operating temperature suffix.
- c. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
- d. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this datasheet.
- e. Guaranteed by design, not subject to production test.
- f. V_{IN} = Input voltage to perform proper function.



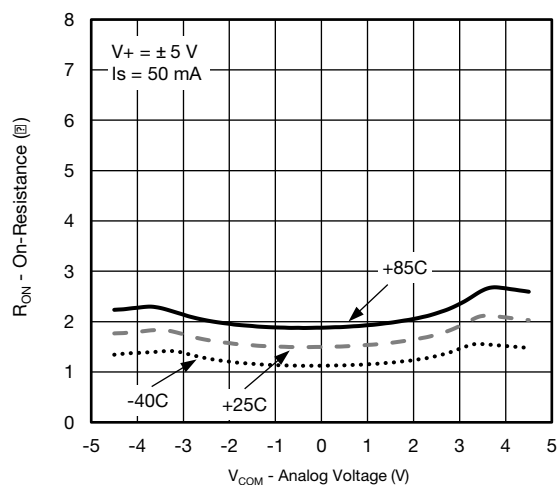
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



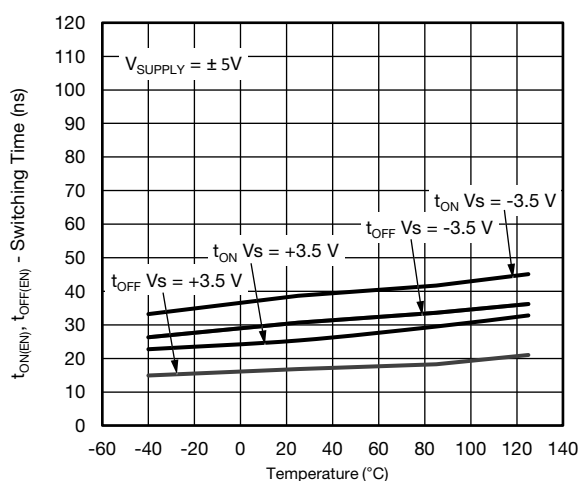
RON vs. VCOM and Supply Voltage



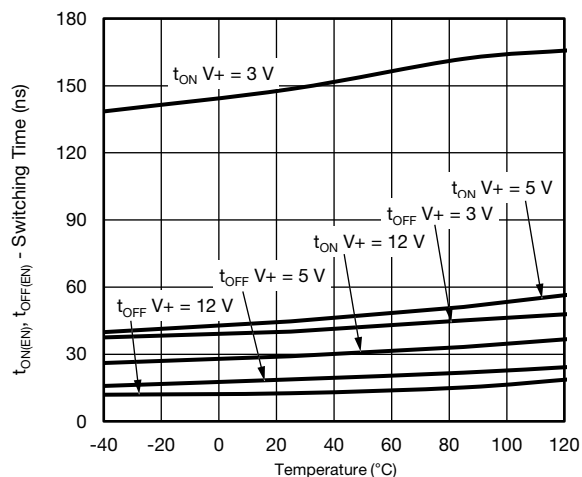
RON vs. Analog Voltage and Temperature



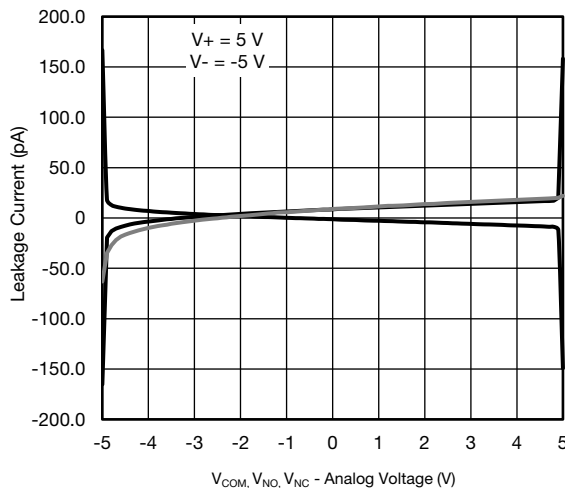
RON vs. Analog Voltage and Temperature



Switching Time vs. Temperature and Dual Supply Voltage



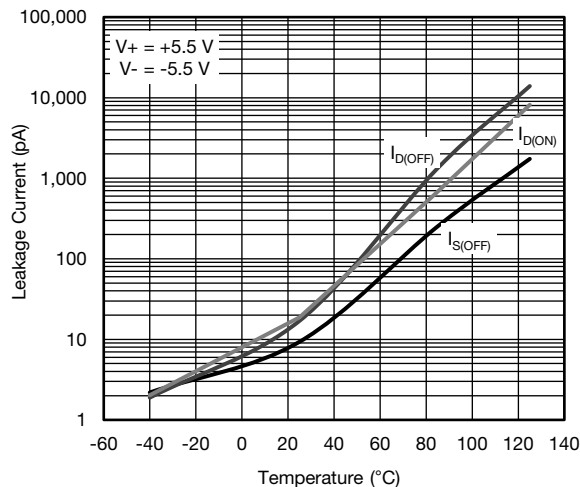
Switching Time vs. Temperature and Single Supply Voltage



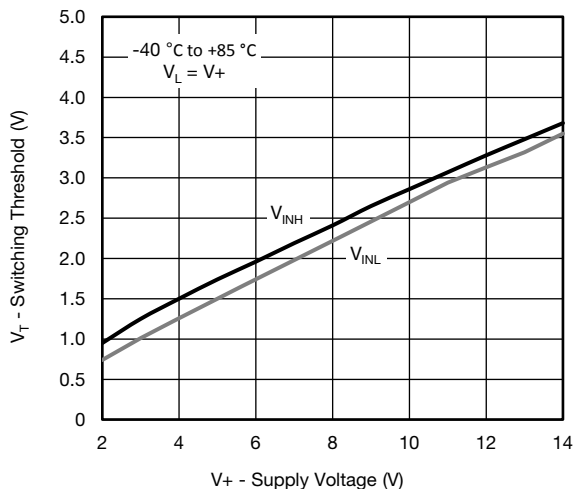
Leakage Current vs. Analog Voltage



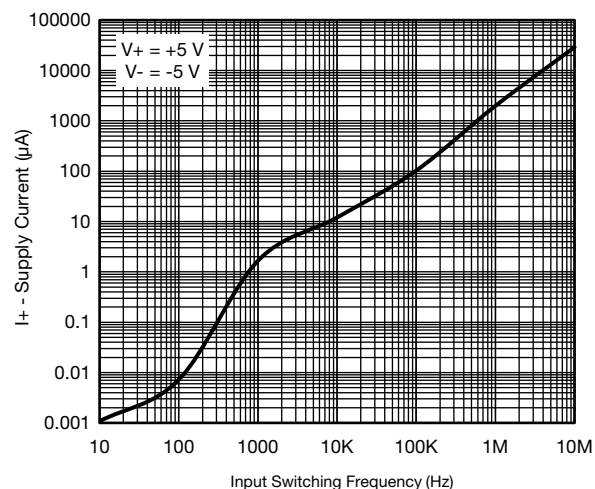
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



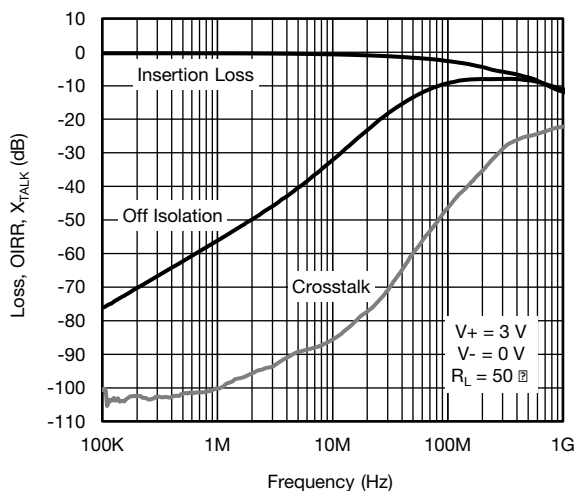
Leakage Current vs. Temperature



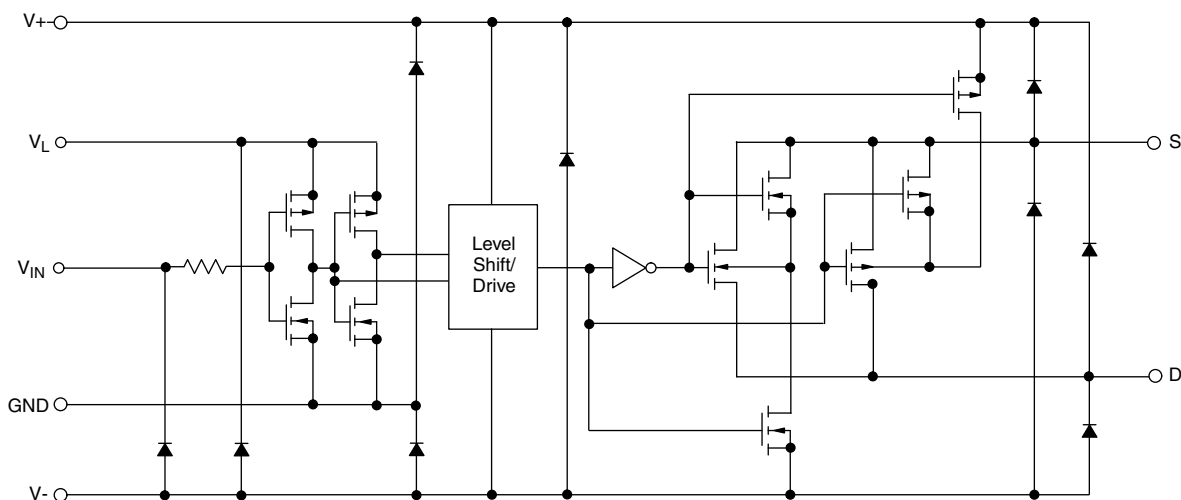
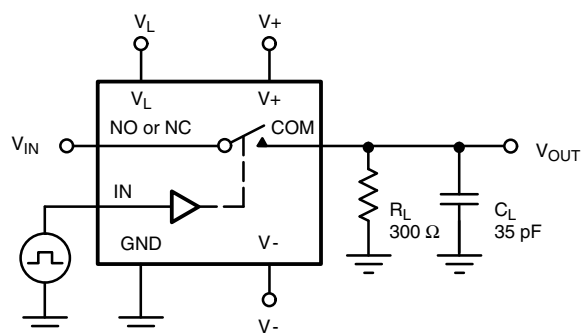
Switching Threshold vs. Supply Voltage



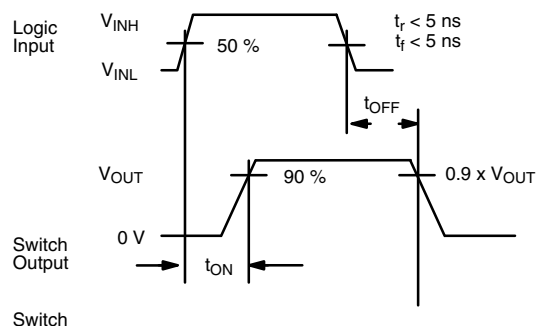
Switching Current vs. Input Switching Frequency



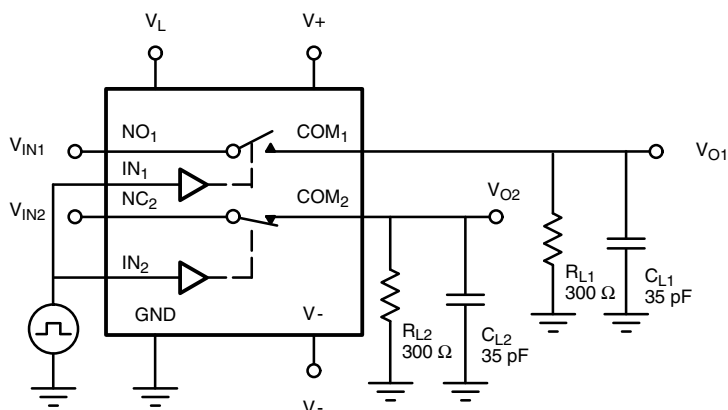
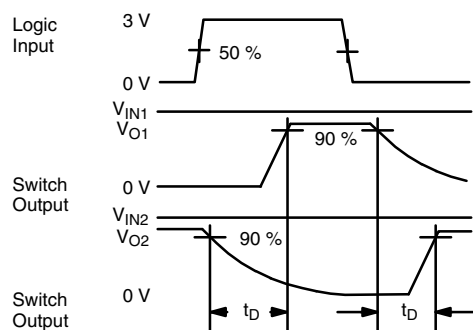
Insertion Loss, Off Isolation and Crosstalk vs. Frequency

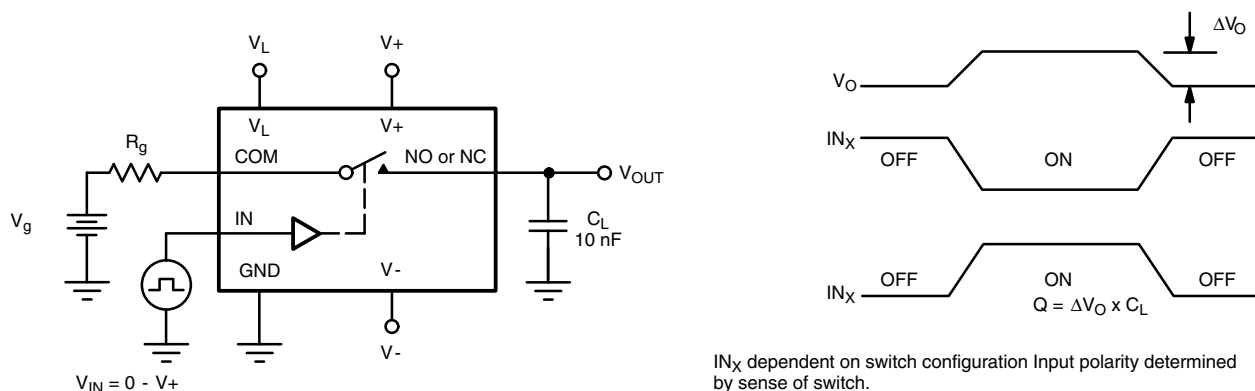
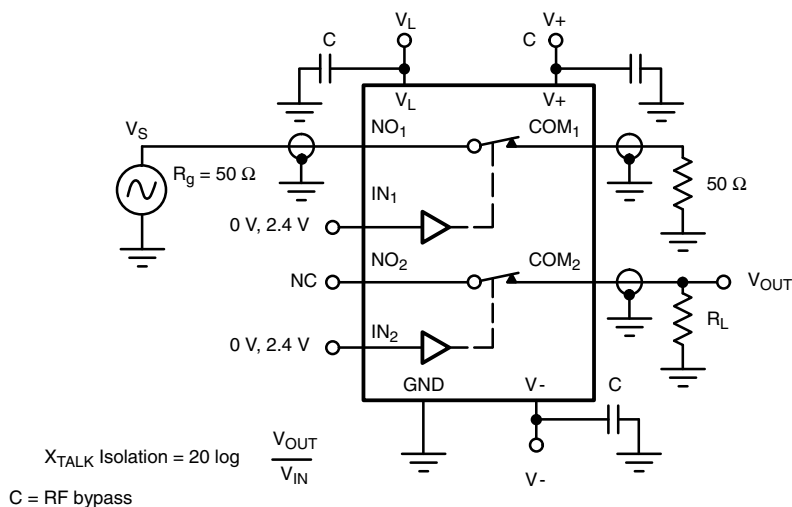
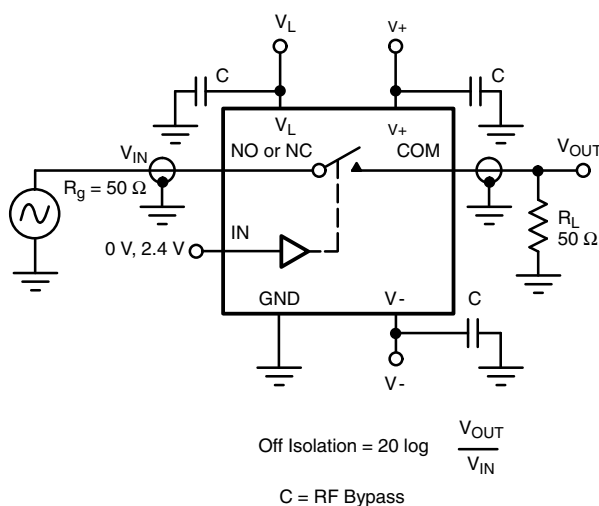
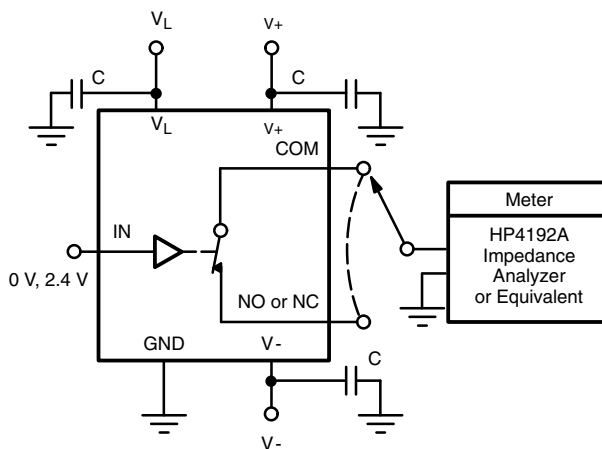
SCHEMATIC DIAGRAM (typical channel)

Fig. 1
TEST CIRCUITS

 C_L (includes fixture and stray capacitance)

$$V_{OUT} = V_{IN} \frac{R_L}{R_L + r_{ON}}$$



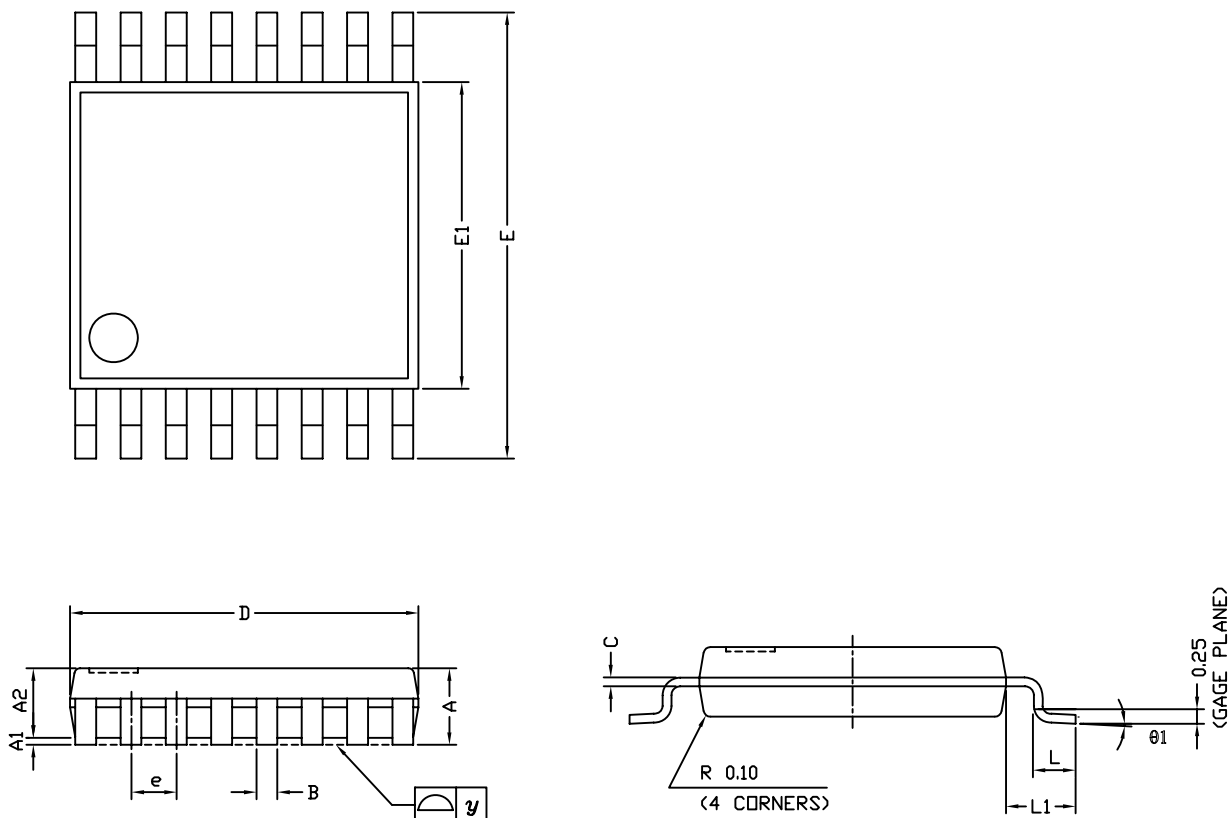
Note: Logic input waveform is inverted for switches that have the opposite logic sense control

Fig. 2 - Switching Time

 C_L (includes fixture and stray capacitance)

Fig. 3 - Break-Before-Make (DG9426E)

TEST CIRCUITS

Fig. 4 - Charge Injection

Fig. 5 - Crosstalk

Fig. 6 - Off-Isolation

Fig. 7 - Source/Drain Capacitances

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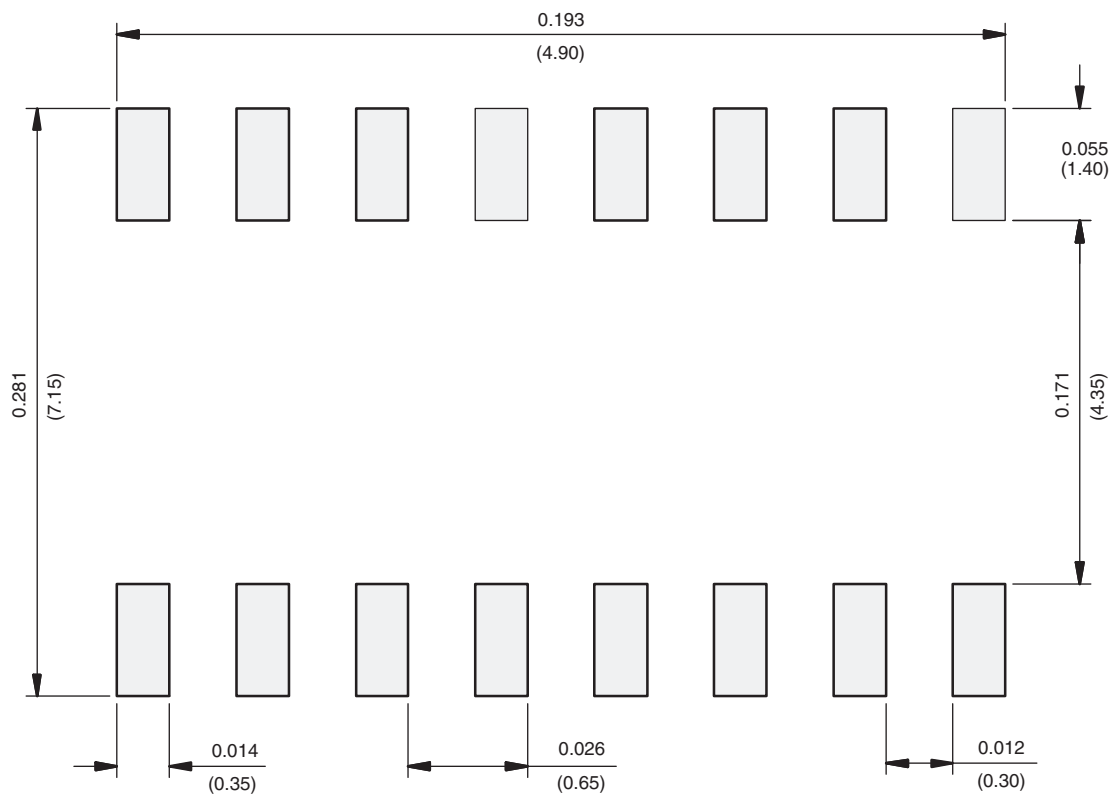
TSSOP: 16-LEAD



Symbols	DIMENSIONS IN MILLIMETERS		
	Min	Nom	Max
A	-	1.10	1.20
A1	0.05	0.10	0.15
A2	-	1.00	1.05
B	0.22	0.28	0.38
C	-	0.127	-
D	4.90	5.00	5.10
E	6.10	6.40	6.70
E1	4.30	4.40	4.50
e	-	0.65	-
L	0.50	0.60	0.70
L1	0.90	1.00	1.10
y	-	-	0.10
θ1	0°	3°	6°
ECN: S-61920-Rev. D, 23-Oct-06			
DWG: 5624			



RECOMMENDED MINIMUM PAD FOR TSSOP-16



Recommended Minimum Pads
Dimensions in inches (mm)



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В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

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